

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of)
)
	Toshiki Makimoto, et al.)
)
Serial No.:	10/516,380) Art Unit
) 2818
Filing Date:	November 30, 2004)
)
Confirmation No.:	2860)
)
For:	P-TYPE NITRIDE SEMICONDUCTOR)
	STRUCTURE AND BIPOLAR TRANSISTOR)
)
Examiner:	Tram Hoang Nguyen)

AMENDMENT "E" AND RESPONSE TO OFFICE ACTION

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Examiner:

Applicant submits this paper in response to the Office Action mailed October 30, 2008.
Reconsideration is respectfully requested in view of the following remarks:

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 6 of this paper.